

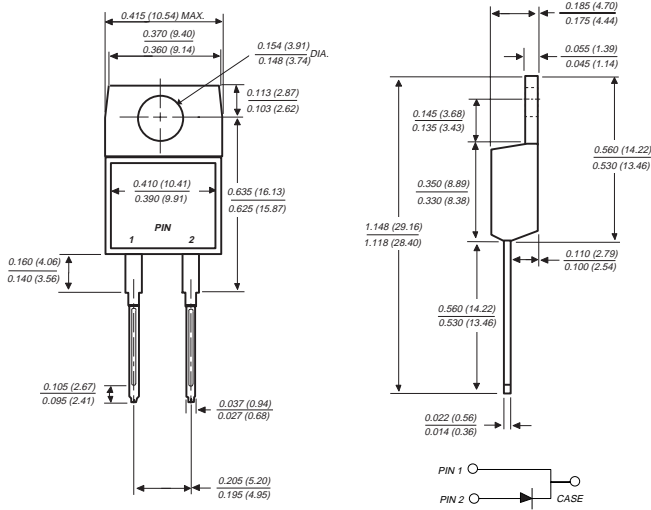
# MBR1035 THRU MBR1060

## SCHOTTKY RECTIFIER

Reverse Voltage - 35 to 60 Volts

Forward Current - 10.0 Amperes

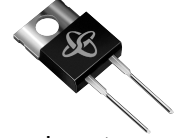
### TO-220AC



Dimensions in inches and (millimeters)

### FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ High current capability, low forward voltage drop
- ◆ High surge capability
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆ Guardring for overvoltage protection
- ◆ High temperature soldering guaranteed: 250°C/10 seconds, 0.25" (6.35mm) from case



### MECHANICAL DATA

**Case:** JEDEC TO-220AC molded plastic body  
**Terminals:** Leads solderable per MIL-STD-750, Method 2026

**Polarity:** As marked

**Mounting Position:** Any

**Mounting Torque:** 5 in. - lbs. max.

**Weight:** 0.08 ounces, 1.81 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	MBR1035	MBR1045	MBR1050	MBR1060	UNITS
Maximum repetitive peak reverse voltage	$V_{RRM}$	35	45	50	60	Volts
Maximum working peak reverse voltage	$V_{RWM}$	35	45	50	60	Volts
Maximum DC blocking voltage	$V_{DC}$	35	45	50	60	Volts
Maximum average forward rectified current (SEE FIG. 1)	$I_{(AV)}$	10.0				Amps
Peak repetitive forward current at $T_C=135^\circ\text{C}$ (square wave 20 KHz)	$I_{FRM}$	20.0				Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	150.0				Amps
Peak repetitive reverse surge current (NOTE 1)	$I_{RRM}$	1.0	0.5			Amps
Voltage rate of change (rated $V_R$ )	$dv/dt$	10,000				$V_{\mu s}$
Maximum instantaneous forward voltage at (NOTE 2) $I_F=10A, T_C=25^\circ\text{C}$ $I_F=10A, T_C=125^\circ\text{C}$ $I_F=20A, T_C=25^\circ\text{C}$ $I_F=20A, T_C=125^\circ\text{C}$	$V_F$	- 0.57 0.84 0.72	0.80 0.70 0.95 0.85			Volts
Maximum instantaneous reverse current at rated DC blocking voltage $T_C=25^\circ\text{C}$ (NOTE 2) $T_C=125^\circ\text{C}$	$I_R$	0.10 15.0				mA
Maximum thermal resistance, junction to case	$R_{\theta JC}$	2.0				$^\circ\text{C/W}$
Operating junction temperature range	$T_J$	-65 to +150				$^\circ\text{C}$
Storage temperature range	$T_{STG}$	-65 to +175				$^\circ\text{C}$

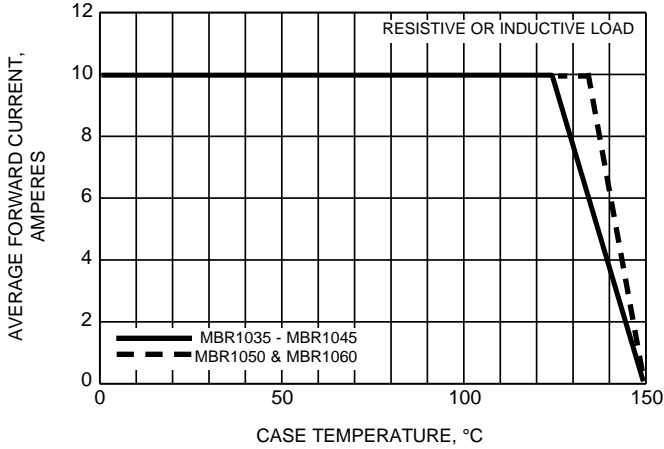
#### NOTES:

(1) 2.0 $\mu s$  pulse width,  $f=1.0$  KHz

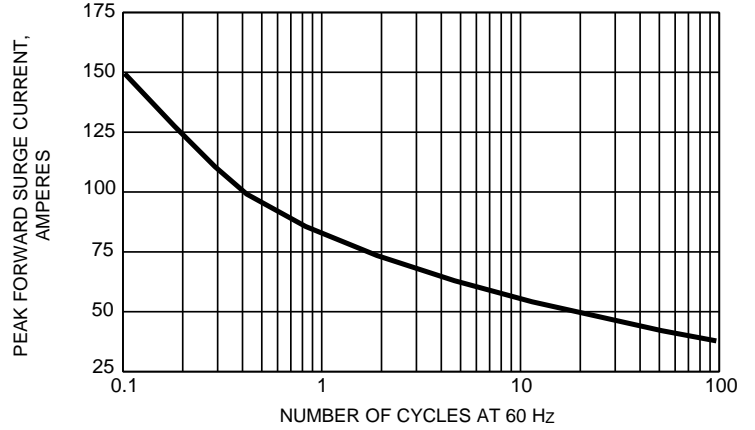
(2) Pulse test: 300 $\mu s$  pulse width, 1% duty cycle

# RATINGS AND CHARACTERISTIC CURVES MBR1035 THRU MBR1060

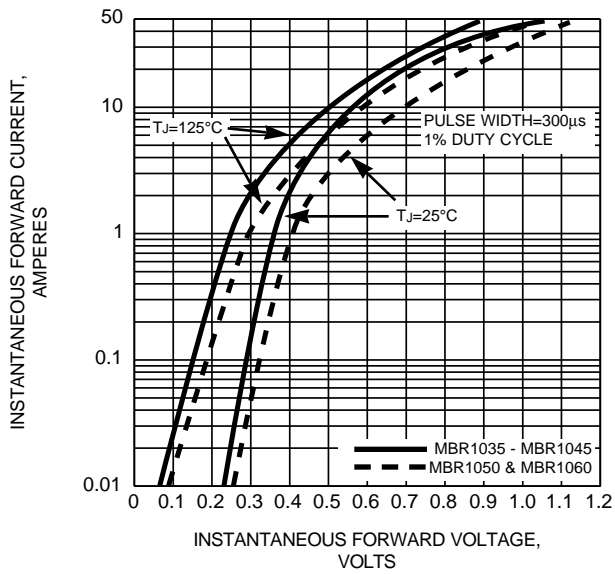
**FIG. 1 - FORWARD CURRENT DERATING CURVE**



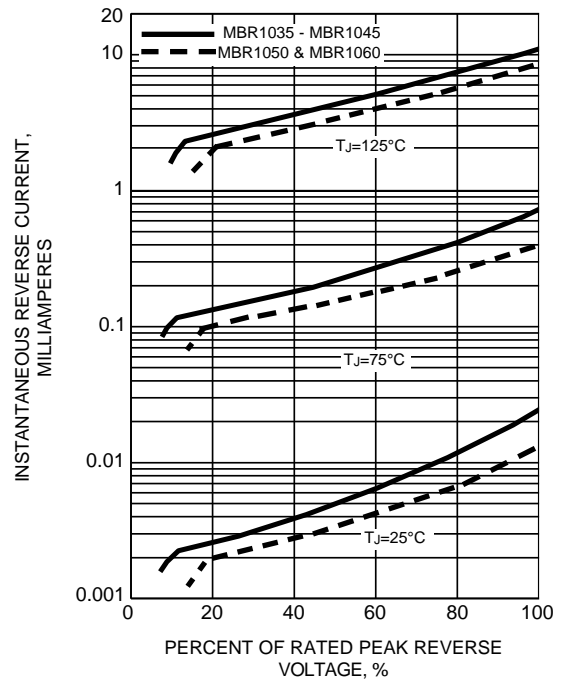
**FIG. 2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT**



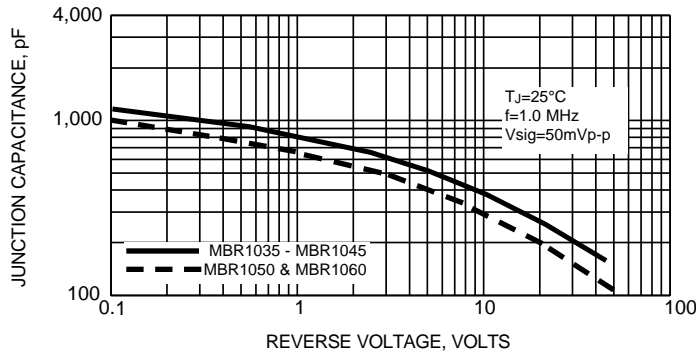
**FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS**



**FIG. 4 - TYPICAL REVERSE CHARACTERISTICS**



**FIG. 5 - TYPICAL JUNCTION CAPACITANCE**



**FIG. 6 - TYPICAL TRANSIENT THERMAL IMPEDANCE**

